

28–32 GHz GaAs MMIC Driver Amplifier



AA031P1-00

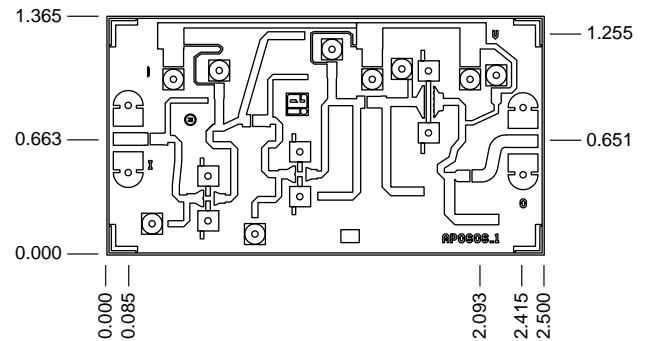
Features

- Single Bias Supply Operation (5 V)
- 19 dB Typical Small Signal Gain
- 16 dBm Typical $P_{1\text{ dB}}$ Output Power at 28 GHz
- 0.25 μm Ti/Pd/Au Gates
- 100% On-Wafer RF and DC Testing
- 100% Visual Inspection to MIL-STD-883 MT 2010

Description

Alpha's three-stage reactively-matched 28–32 GHz GaAs MMIC driver amplifier has typical small signal gain of 19 dB with a typical $P_{1\text{ dB}}$ of 16 dBm at 28 GHz. The chip uses Alpha's proven 0.25 μm MESFET technology, and is based upon MBE layers and electron beam lithography for the highest uniformity and repeatability. The FETs employ surface passivation to ensure a rugged, reliable part with through-substrate via holes and gold-based backside metallization to facilitate a conductive epoxy die attach process. All chips are screened for gain, output power and S-parameters prior to shipment for guaranteed performance. Designed for 28–32 GHz LMDS and digital radio bands.

Chip Outline



Dimensions indicated in mm.
All DC (V) pads are 0.1 x 0.1 mm and RF In, Out pads are 0.07 mm wide.
Chip thickness = 0.1 mm.

Absolute Maximum Ratings

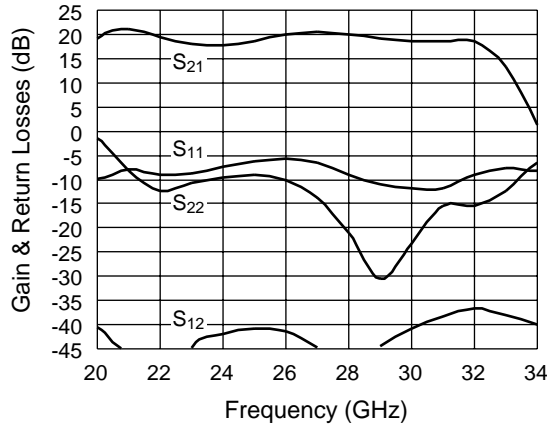
Characteristic	Value
Operating Temperature (T_C)	-55°C to +90°C
Storage Temperature (T_{ST})	-65°C to +150°C
Bias Voltage (V_D)	7 V_{DC}
Power In (P_{IN})	16 dBm
Junction Temperature (T_J)	175°C

Electrical Specifications at 25°C ($V_{DS} = 5\text{ V}$)

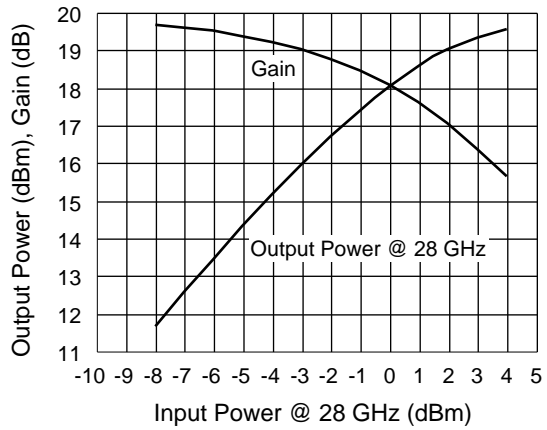
Parameter	Condition	Symbol	Min.	Typ. ²	Max.	Unit
Drain Current		I_{DS}		145	200	mA
Small Signal Gain	$F = 28\text{--}32\text{ GHz}$	G	17	19		dB
Input Return Loss	$F = 28\text{--}32\text{ GHz}$	RL_I		-10	-6	dB
Output Return Loss	$F = 28\text{--}32\text{ GHz}$	RL_O		-15	-10	dB
Output Power at 1 dB Gain Compression	$F = 28\text{ GHz}$	$P_{1\text{ dB}}$	14	16		dBm
Saturated Output Power	$F = 28\text{ GHz}$	P_{SAT}	15	18		dBm
Thermal Resistance ¹		θ_{JC}		101		°C/W

1. Calculated value based on measurement of discrete FET.
2. Typical represents the median parameter value across the specified frequency range for the median chip.

Typical Performance Data

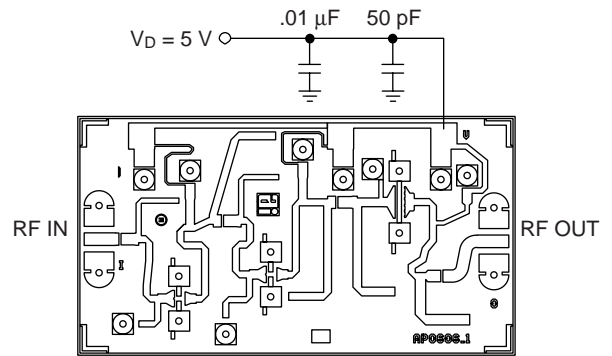


Typical Small Signal Performance S-Parameters (V_{DS} = 5 V)



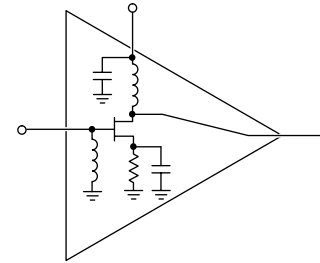
Typical Power Sweep (V_{DS} = 5 V)

Bias Arrangement



For biasing on, adjust V_{DS} from zero to the desired value (5 V recommended). For biasing off, reverse the biasing on procedure.

Circuit Schematic



Detail A

